

SLLSE29 A - APRIL 2010-REVISED FEBRUARY 2012

# **Dual Channel USB3.0 Redriver/Equalizer**

Check for Samples: SN65LVPE502

### **FEATURES**

- Single Lane USB 3.0 Equalizer/Redriver
- Selectable Equalization, De-emphasis and Output Swing Control
- Integrated Termination
- Hot-Plug Capable
- Receiver Detect
- Low Power:
  - 315mW(TYP), V<sub>CC</sub> = 3.3V
- Auto Low Power Modes:
  - 5mW (TYP) When no Connection Detected
  - 70mW (TYP) When in U2/U3 Mode

- Excellent Jitter and Loss Compensation Capability: to 24"
  - 24" of 6 mil Stripline on FR4
  - 12" on Input and 4m, 26AWG USB 3.0 Cable on Output
- Small foot print 24 Pin (4mm × 4mm) QFN Package
- High Protection Against ESD Transient
  HBM: 5,000 V
  - CDM: 1,500 V
  - MM: 200 V

### APPLICATIONS

 Notebooks, Desktops, Docking Stations, Backplane and Cabled Application

### DESCRIPTION

The SN65LVPE502 is a dual channel, single lane USB 3.0 redriver and signal conditioner supporting data rates of 5.0Gbps. The device complies with USB 3.0 spec revision 1.0, supporting electrical idle condition and low frequency periodic signals (LFPS) for USB 3.0 power management modes.

### Programmable EQ, De-Emphasis and Amplitude Swing

The SN65LVPE502 is designed to minimize signal degradation effects such as crosstalk and inter-symbol interference (ISI) that limits the interconnect distance between two devices. The input stage of each channel offers selectable equalization settings that can be programmed to match loss in the channel. The differential outputs provide selectable de-emphasis to compensate for the anticipated distortion USB 3.0 signal will experience. Level of de-emphasis will depend on the length of interconnect and its characteristics. The SN65LVPE502 provides a unique way to tailor output de-emphasis on a per channel basis with use of DE and OS pins. All Rx and Tx equalization settings supported by the device are programmed by six 3-state pins as shown in Table 2.

### Low Power Modes

The device supports three low power modes as described below.

1. Sleep Mode

Initiated anytime EN\_RXD undergoes a high to low transition or when device powers up with EN\_RXD set low. In sleep mode both input and output terminations are held at HiZ and device ceases operation to conserve power. Sleep mode max power consumption is 1mW, entry time is 2µs, device exits sleep mode to Rx.Detect mode after EN\_RXD is driven to  $V_{CC}$ , exit time is 100µs max.

2. RX Detect Mode - When no remote device is connected

Anytime SN65LVPE502 detects a break in link (i.e., when upstream device is disconnected) or after powerup fails to find a remote device, SN65LVPE502 goes to Rx Detect mode and conserves power by shutting down majority of the internal circuitry. In this mode, input termination for both channels are driven to Hi-Z. In Rx Detect mode device power is <10mW(TYP) or less than 5% of its normal operating power This feature is useful in saving system power in mobile applications like notebook PC where battery life is critical.

Anytime an upstream device gets reconnected the redriver automatically senses the connection and goes to normal operating mode. This operation requires no setting to the device.



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3. U2/U3 Mode

With the help of internal timers the device tracks when link enters USB 3.0 low power modes U2 and U3, in these modes link is in electrical idle state. SN65LVPE502 will selectively turn-off internal circuitry to save on power. Typical power saving is about 75% lower than normal operating mode. The device will automatically revert to active mode when signaling activity (LFPS) is detected.



These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

## **DESCRIPTION CONTINUED**

### **Receiver Detection**

RX.Detect cycle is performed by first setting Rx termination for each channel to Hi-Z, device then starts sensing for receiver termination that may be attached at the other end of each TX.

If receiver is detected on both channel:

The TX and RX terminations are switched to Z<sub>DIFF-TX</sub>, Z<sub>DIFF-RX</sub>, respectively

If no receiver is detected on one or both channels:

- The transmitter is pulled to Hi-Z
- · The channel is put in low power mode
- Device attempts to detect Rx termination in 12 ms (TYP) interval until termination is found or the device is put in sleep mode.

#### **USB Compliance Mode**

The device enters USB compliance mode when both EN\_RXD and CM pins are set H. This mode is used to test the transmitter for compliance to voltage and timing specifications per USB 3.0 compliance specs. In this mode each channel will maintain its low-impedance termination  $R_{DC-RX}$ , while auto Rx detect operation in the device is disabled.

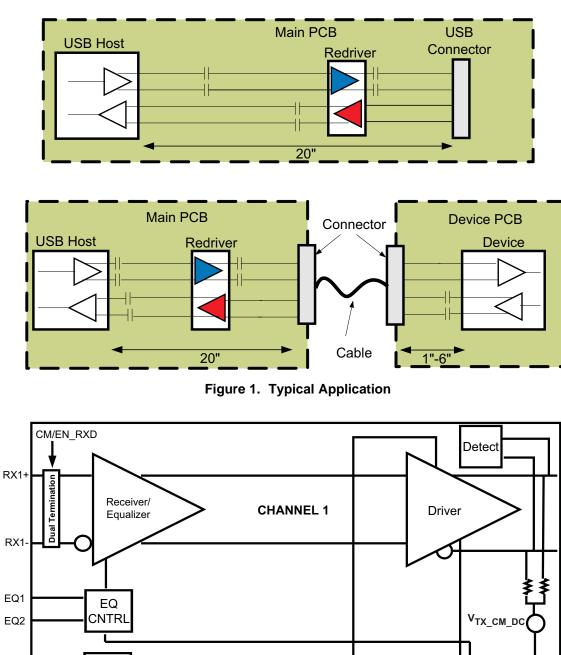
#### **Electrical Idle Support**

The electrical idle support is needed for low frequency periodic signaling (LFPS) used in USB 3.0 side band communication. A link is in an electrical idle state when the TX± voltage is held at a steady constant value like the common mode voltage. SN65LVPE502 detects an electrical idle state when RX± voltage at the device pin falls below  $V_{RX\_IDLE\_DIFFpp}$  min. After detection of an idle state in a given channel the device asserts electrical idle state in its corresponding TX. When RX± voltage exceeds  $V_{RX\_IDLE\_DIFFpp}$  max normal operation is restored and output start passing input signal. The electrical idle exit and entry time is specified at ≤6 ns.



TX1+

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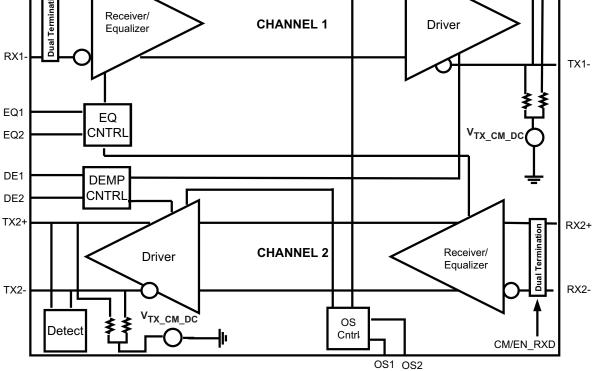


Figure 2. Data FLow Block Diagram

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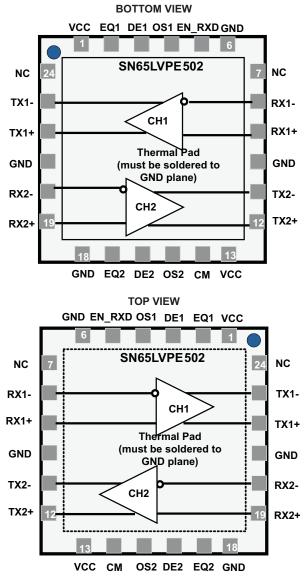


Figure 3. Flow-Through Pin-Out

Table 1. Pin Descriptio	n
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PIN NUMBER NAME							
		I/O TYPE	DESCRIPTION				
HIGH SPEED D	DIFFERENTIAL	I/O PINS					
8	RX1–	I, CML					
9	RX1+	I, CML	Non-inverting and inverting CML differential input for CH 1 and CH 2. These pins are tied to				
20	RX2–	I, CML	an internal voltage bias by dual termination resistor circuit				
19	RX2+	I, CML					
23	TX1–	O, VML					
22	TX1+	O, VML	Non-inverting and inverting VML differential output for CH 1 and CH 2. These pins are				
11	TX2–	O, VML	internally tied to voltage bias by termination resistors				
12	TX2+	O, VML					



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#### Table 1. Pin Description (continued)

ND		
Pads not internally connected		
to V <sub>CC</sub> /2		
to V <sub>CC</sub> /2		
<sub>CC</sub> /2		

(1) Internally biased to  $V_{CC}/2$  with >200k $\Omega$  pull-up/pull-down. When pins are left as NC board leakage at this pin pad must be < 1  $\mu$ A otherwise drive to  $V_{CC}/2$  to assert mid-level state.

os	x <sup>(1)</sup>		IT AMPLITUDE nVpp)		
NC (c	lefault)	1000			
	0	87	70		
	1	10	85		
EQ	x <sup>(1)</sup>	EQUALIZ	ATION dB		
NC (c	lefault)	(	)		
	0	-	7		
	1	15			
DEx <sup>(1)</sup>	OSx <sup>(1)</sup> = NC	OSx <sup>(1)</sup> = 0	OSx <sup>(1)</sup> = 1		
NC	–3.5 dB	–2.2 dB	-4.4 dB		
0	-6.0 dB	–5.2 dB	–6.0 dB		
1	–8.5 dB	–8.9 dB	–7.6 dB		
EN_	RXD	DEVICE F	UNCTION		
1 (de	efault)	Normal ope	rating mode		
	0	Sleep mode			
C	M	DEVICE F	UNCTION		
0 (de	efault)	Normal Mode			
	1	Compliar	nce mode		

#### **Table 2. Signal Control Pin Setting**

(1) Applies to Channel 1 and Channel 2 at 2.5 GHz.

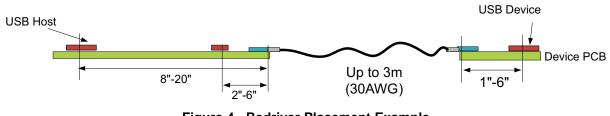


Figure 4. Redriver Placement Example

#### **ORDERING INFORMATION**<sup>(1)</sup>

PART NUMBER	PART MARKING	PCAKAGE
SN65LVPE502RGER	LVPE502	24-pin RGE Reel (large)
SN65LVPE502RGET	LVPE502	24-pin RGE Reel (small)

(1) For the most current package and ordering information, see the Package Option Addendum at the end of this document, or see the TI web site at www.ti.com.

### **ABSOLUTE MAXIMUM RATINGS**

over operating free-air temperature range (unless otherwise noted)<sup>(1)</sup>

		UNITS / VALUES
Supply Voltage Range <sup>(2)</sup>	V <sub>CC</sub>	–0.5 V to 4 V
Valtaga Danga	Differential I/O	–0.5 V to 4 V
Voltage Range	Control I/O	–0.5 V to V <sub>CC</sub> + 0.5V
	Human Body Model <sup>(3)</sup>	±5000V
Electrostatic discharge	Charged Device Model <sup>(4)</sup>	±1500V
	Machine Model <sup>(5)</sup>	±200V
Continuous power dissipation		See Dissipation Rating Table

Stresses beyond those listed under absolute maximum ratings may cause permanent damage to the device. These are stress ratings (1) only and functional operation of the device at these or any conditions beyond those indicated under recommended operating conditions is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

All voltage values, except differential voltages, are with respect to network ground terminal. (2)

(3) Tested in accordance with JEDEC Standard 22, Test Method A114-B.

Tested in accordance with JEDEC Standard 22, Test Method C101-A. Tested in accordance with JEDEC Standard 22, Test Method A115-A. (4)

(5)

## PACKAGE CHARACTERIZATION

over operating free-air temperature range (unless otherwise noted)

	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
P <sub>D</sub>	Device power dissipation	CM, EN_RXD, EQ cntrl pins = NC, K28.5 pattern at 5 Gbps, $V_{ID}$ = 1000 mVpp		330	450	mW
$P_{SD}$	Device power dissipation under low power mode	EN_RXD= GND		0.3	1	mW

### THERMAL INFORMATION

		SN65LVPE502	
	THERMAL METRIC <sup>(1)</sup>	RGE	UNITS
		24 PINS	
$\theta_{JA}$	Junction-to-ambient thermal resistance	46	
$\theta_{\text{JC(TOP)}}$	Junction-to-case(top) thermal resistance	42	
$\theta_{JB}$	Junction-to-board thermal resistance	13	°C/W
ΨJT	Junction-to-top characterization parameter	0.5	C/VV
Ψ <sub>JB</sub>	Junction-to-board characterization parameter	9	
$\theta_{\text{JC(BOTTOM)}}$	Junction-to-case(bottom) thermal resistance	4	

(1) For more information about traditional and new thermal metrics, see the IC Package Thermal Metrics application report, SPRA953.



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### **RECOMMENDED OPERATING CONDITIONS**

over operating free-air temperature range (unless otherwise noted)

		MIN	TYP	MAX	UNIT
V <sub>CC</sub>	Supply Voltage	3	3.3	3.6	V
C <sub>COUPLING</sub>	AC Coupling Capacitor	75		200	nF
	Operating free-air temperature	0		85	°C

### **DEVICE POWER**

The SN65LVPE502 is designed to operate from a single 3.3 V supply.

### **ELECTRICAL CHARACTERISTICS**

over operating free-air temperature range (unless otherwise noted)

	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT		
DEVICE PARAM	<b>NETERS</b>							
I <sub>CC</sub>		EN_RXD, CM, EQ cntrl = NC, K28.5 pattern at 5 Gbps, V <sub>ID</sub> = 1000 mV <sub>pp</sub>		100	120			
ICC <sub>Rx.Detect</sub>	Supply Current	In Rx.Detect mode	2			mA		
ICC <sub>sleep</sub>		EN_RXD = GND			0.1			
ICC <sub>U2-U3</sub>		Link in USB low power state		21				
	Maximum Data Rate				5	Gbps		
t <sub>ENB</sub>	Device Enable Time	Sleep mode exit time EN_RXD L $\rightarrow$ H With Rx termination present			100	μs		
t <sub>DIS</sub>	Device Disable Time	Sleep mode entry time EN_RXD $H \rightarrow L$			2	μs		
T <sub>RX.DETECT</sub>	Rx.Detect Start Event	Power-up time			100	μs		
CONTROL LOG	IC (under recommended operating cond	litions)			·			
V <sub>IH</sub>	High level Input Voltage		1.4		$V_{CC}$	V		
V <sub>IL</sub>	Low Level Input Voltage		-0.3		0.5	V		
V <sub>HYS</sub>	Input Hysteresis			150		mV		
		OSx, EQx, DEx = $V_{CC}$			30			
I <sub>IH</sub>	High Level Input Current	$EN_RXD = V_{CC}$			1	μA		
		$CM = V_{CC}$			30			
		OSx, EQx, DEx = GND	-30					
I <sub>IL</sub>	Low Level Input Current	EN_RXD = GND	-30			μA		
		CM = GND	-1	-1				
RECEIVER AC/	DC							
Vin <sub>diff_pp</sub>	RX1, RX2 Input Voltage Swing	AC coupled differential RX peak to peak signal	100		1200	mVpp		
V <sub>CM_RX</sub>	RX1, RX2 Common Mode Voltage			3.3		V		
Vin <sub>COM_P</sub>	RX1, RX2 AC Peak common mode voltage	Measured at Rx pins with termination enabled			150	mVP		
Z <sub>DC_RX</sub>	DC common mode impedance		18	26	30	Ω		
Z <sub>diff_RX</sub>	DC differential input impedance		72	80	120	Ω		
Z <sub>RX_High_IMP+</sub>	DC Input High Impedance	Device in sleep mode Rx termination not powered. Measured with respect to GND over 500mV max	50	85		kΩ		
V <sub>RX-LFPS-DETpp</sub>	Low Voltage Periodic Signaling (LFPS) Detect Threshold	Measured at receiver pin, below minimum output is squelched, above max input signal is passed to output	100		300	mVpp		
	Differential Return Loss	50 MHz – 1.25 GHz	10	11		dB		
RL <sub>RX-DIFF</sub>		1.25 GHz – 2.5 GHz	6	7		uБ		
RL <sub>RX-CM</sub>	Common Mode Return Loss	50 MHz – 2.5 GHz	11	13		dB		

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### ELECTRICAL CHARACTERISTICS (continued)

over operating free-air temperature range (unless otherwise noted)

· •	PARAMETER	TEST CONDITIONS	MIN	ТҮР	MAX	UNIT
TRANSMITTER A	C/DC					
		$R_{L}$ =100 $\Omega$ +1%, DEx, OSx = NC, Transition Bit	800	1000	1200	
Vtxdiff_tb_pp Vtxdiff_ntb_pp		$R_{L}$ =100 $\Omega$ +1%, DEx, OSx = GND Transition Bit		870		
	Differential peak-to-peak Output	$R_{L}$ =100 $\Omega$ +1%, DEx, OSx = VCC Transition Bit		1085		
	Voltage (VID = 800, 1200 mVpp, 5Gbps)	$R_L = 100\Omega + 1\%$ , DEx=NC, OSx = 0,1,NC Non-Transition Bit		665		mV
		$R_{L}$ =100 $\Omega$ +1%, DEx=0, OSx = 0,1,NC Non-Transition Bit		510		
		$R_{L}$ =100 $\Omega$ +1%, DEx=1 OSx = 0,1,NC Non-Transition Bit		375		
			-3.0	-3.5	-4.0	
	De-Emphasis Level	OS1,2 = NC (for $OS1,2 = 1$ and 0 see Table 2)		-6.0		dB
				-8.5		
T <sub>DE</sub>	De-Emphasis Width			0.85		UI
Z <sub>diff_TX</sub>	DC Differential Impedance		72	90	120	Ω
Z <sub>CM_TX</sub>	DC Common Mode Impedance	Measured w.r.t to AC ground over 0-500mV	18	23	30	Ω
	Differential Datum Lana	f = 50 MHz – 1.25 GHz	9	10		
RL <sub>diff_TX</sub>	Differential Return Loss	f = 1.25 GHz – 2.5 GHz	6	7		dB
RL <sub>CM_TX</sub>	Common Mode Return Loss	f = 50 MHz – 2.5 GHz	11	12		dB
I <sub>TX_SC</sub>	TX short circuit current	TX± shorted to GND			60	mA
V <sub>TX_CM_DC</sub>	Transmitter DC common-mode voltage		2.0	2.6	3.0	V
V <sub>TX_CM_AC_Active</sub>	TX AC common mode voltage active			30	100	mVpp
V <sub>TX_idle_diff-AC-pp</sub>	Electrical idle differential peak to peak output voltage	HPF to remove DC	0		10	mV
V <sub>TX_CM_DeltaU1-U0</sub>	Absolute delta of DC CM voltage during active and idle states			35	200	mV
V <sub>TX_idle_diff</sub> -DC	DC Electrical idle differential output voltage	Voltage must be low pass filtered to remove any AC component	0		10	mV
V <sub>detect</sub>	Voltage change to allow receiver detect	Positive voltage to sense receiver termination			600	mV
t <sub>R</sub> ,t <sub>F</sub>	Output Rise/Fall time	20%-80% of differential voltage measure 1"	30	50		ps
t <sub>RF_MM</sub>	Output Rise/Fall time mismatch	from the output pin			20	ps
$T_{diff\_LH},T_{diff\_HL}$	Differential Propagation Delay	De-Emphasis = $-3.5$ dB (CH 0 and CH 1). Propagation delay between 50% level at input and output See Figure 5		290	350	ps
t <sub>idleEntry</sub> t <sub>idleExit</sub>	Idle entry and exit times	See Figure 6		4	6	ns
C <sub>TX</sub>	Tx input capacitance to GND	At 2.5 GHz		1.25		pF
EQUALIZATION						
T <sub>TX-EYE</sub> (1)(2)	Total Jitter (Tj) at point A			0.14	0.5	
DJ <sub>TX</sub> <sup>(2)</sup>	Deterministic Jitter (Dj)	Device setting: OS1 = L, DE1 = H, EQ1 = L		0.06	0.3	UIpp <sup>(3)</sup>
RJ <sub>TX</sub> <sup>(2)(4)</sup>	Random Jitter (Rj)			0.08	0.2	
T <sub>TX-EYE</sub> <sup>(1)</sup> <sup>(2)</sup>	Total Jitter (Tj) at point B			0.14	0.5	
DJ <sub>TX</sub> <sup>(2)</sup>	Deterministic Jitter (Dj)	Device setting: OS2 = H, DE2 = H, EQ2 = L		0.06	0.3	Ulpp <sup>(3)</sup>
RJ <sub>TX</sub> <sup>(2)(4)</sup>	Random Jitter (Rj)			0.08	0.2	

Includes Rj at 10<sup>-12</sup> (1)

Measured at the end of reference channel in Figure 8 with K28.5 pattern, VID=1000mVpp, 5Gbps, -3.5dB DE from source. (2)

UI = 200ps

(3) (4) Rj calculated as 14.069 times the RMS random jitter for 10<sup>-12</sup> BER

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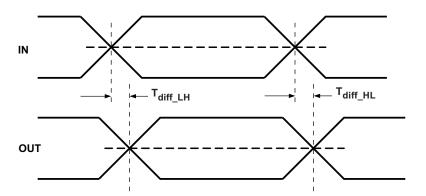


Figure 5. Propagation Delay

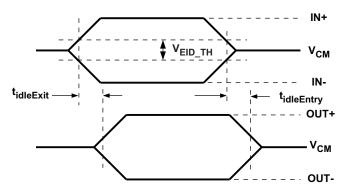


Figure 6. Electrical Idle Mode Exit and Entry Delay

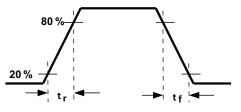


Figure 7. Output RIse and Fall Times



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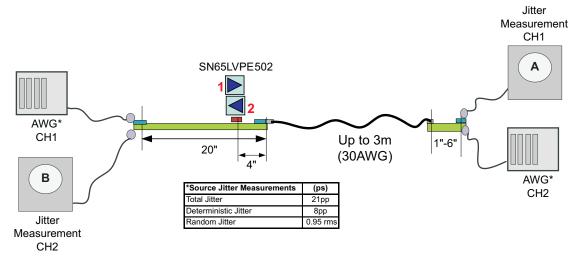


Figure 8. Jitter Measurement Setup

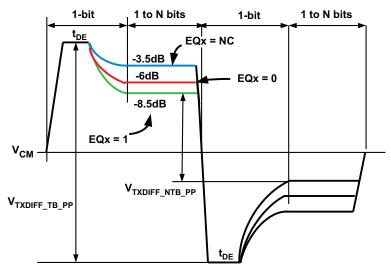


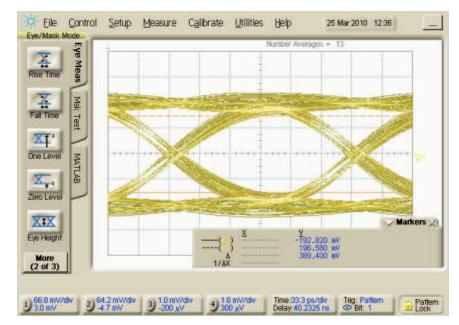
Figure 9. Output De-Emphasis Levels OSx = NC



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#### **Typical Eye Diagram and Performance Curves**

Input Signal Characteristics: Data Rate = 5 Gbps,  $V_{ID}$  = 1000 mVpp, DE = -3.5 dB, Pattern = K28.5 Device Operating Conditions: VCC = 3.3 V, Temp = 25°C



#### Input Trace Length Held Constant and Output Cable Length Varied

Figure 10. Input Trace = 12 Inches, 6 mil and Output USB 3 Cable Length = 1 M

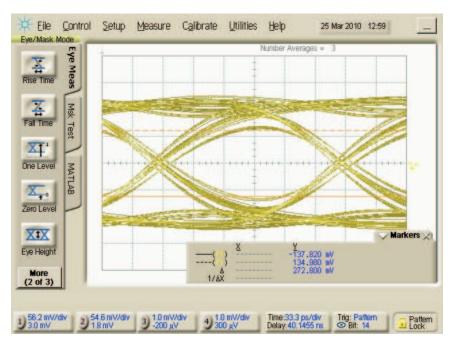


Figure 11. Input Trace = 12 Inches, 6 mil and Output USB 3 Cable Length = 2 M



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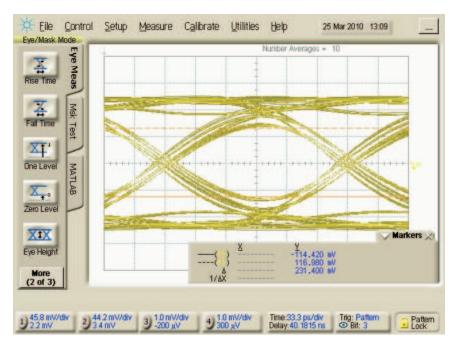


Figure 12. Input Trace = 12 Inches, 6 mil and Output USB 3 Cable Length = 3 M

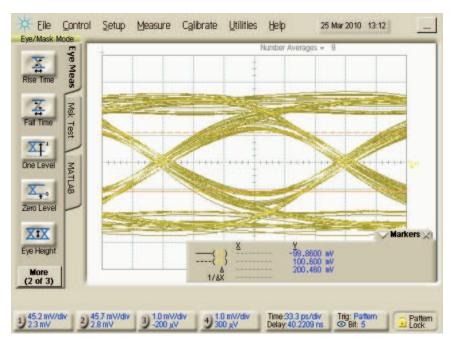


Figure 13. Input Trace = 12 Inches, 6 mil and Output USB 3 Cable Length = 4 M

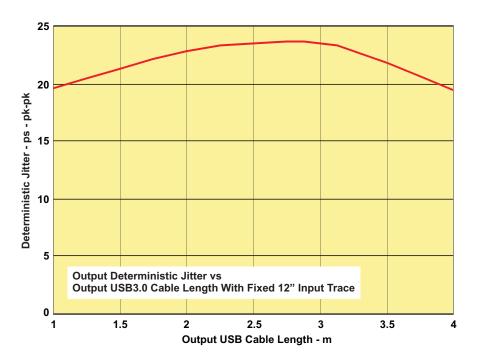


Figure 14. Jitter Performance Over Different Cable Lengths

### Input Trace Length Held Constant and Output Trace Varied

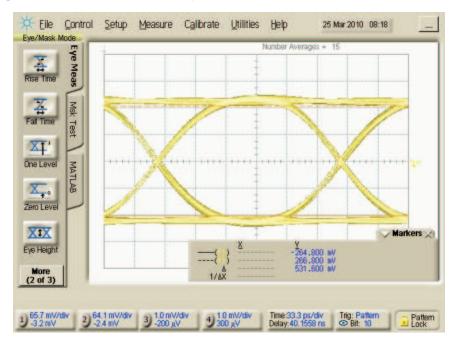


Figure 15. Input Trace = 4 Inches, 6 mil and Output Trace = 4 Inches, 6 mil

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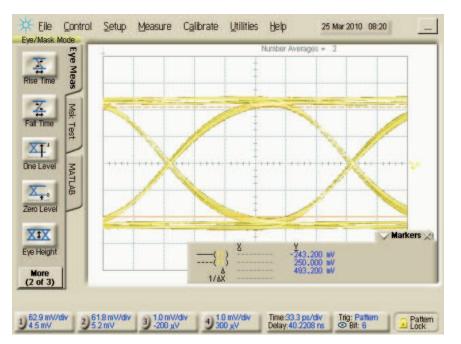


Figure 16. Input Trace = 4 Inches, 6 mil and Output Trace = 8 Inches, 6 mil

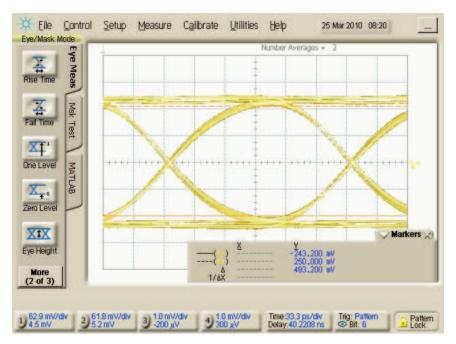


Figure 17. Input Trace = 4 Inches, 6 mil and Output Trace = 12 Inches, 6 mil



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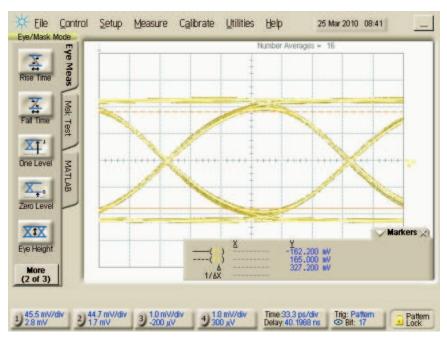


Figure 18. Input Trace = 4 Inches, 6 mil and Output Trace = 16 Inches, 6 mil

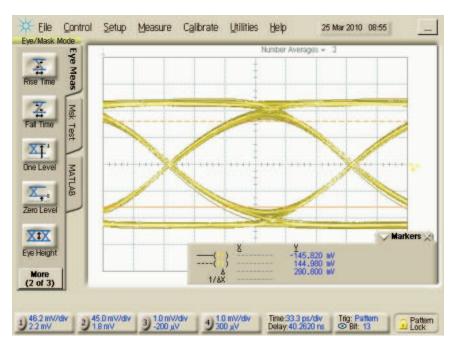


Figure 19. Input Trace = 4 Inches, 6 mil and Output Trace = 20 Inches, 6 mil

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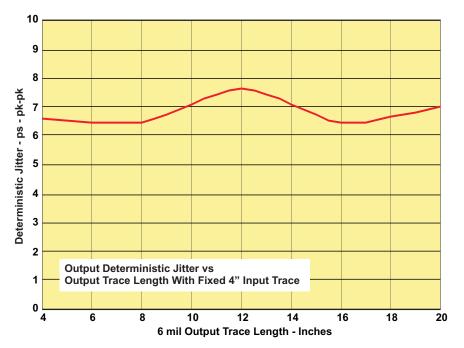


Figure 20. Jitter Performance Over Different Output Trace Lengths

## **Output Trace Length Held Constant and Input Trace Length Varied**

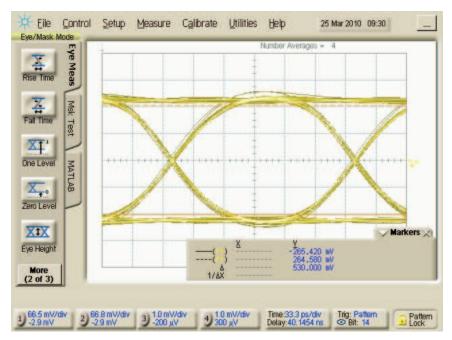


Figure 21. Input Trace = 4 Inches, 6 mil and Output Trace = 4 Inches, 6 mil



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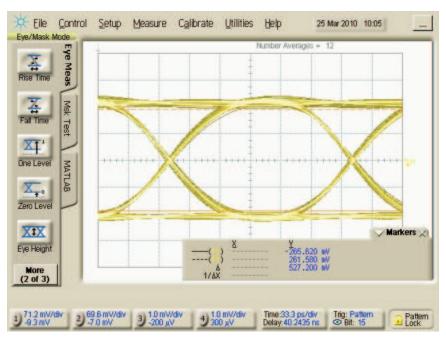


Figure 22. Input Trace = 8 Inches, 6 mil and Output Trace = 4 Inches, 6 mil

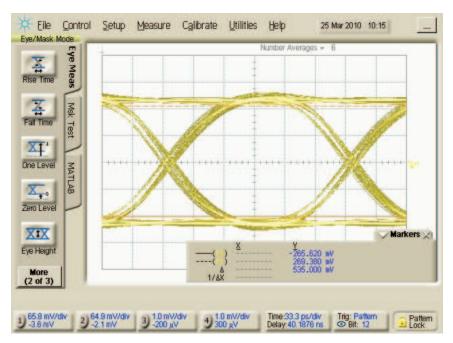


Figure 23. Input Trace = 12 Inches, 6 mil and Output Trace = 4 Inches, 6 mil



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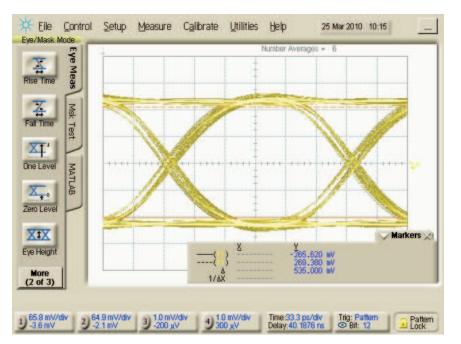


Figure 24. Input Trace = 16 Inches, 6 mil and Output Trace = 4 Inches, 6 mil

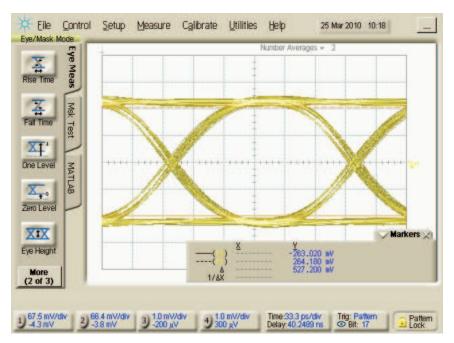


Figure 25. Input Trace = 20 Inches, 6 mil and Output Trace = 4 Inches, 6 mil



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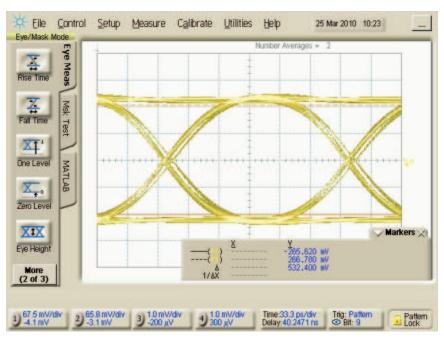


Figure 26. Input Trace = 28 Inches, 6 mil and Output Trace = 4 Inches, 6 mil

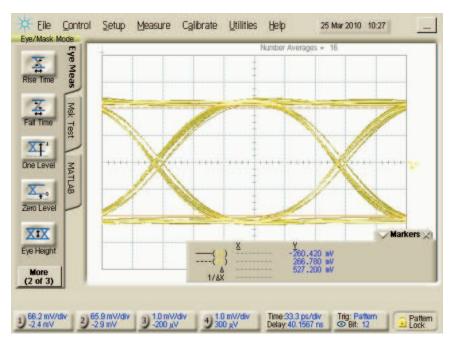


Figure 27. Input Trace = 32 Inches, 6 mil and Output Trace = 4 Inches, 6 mil



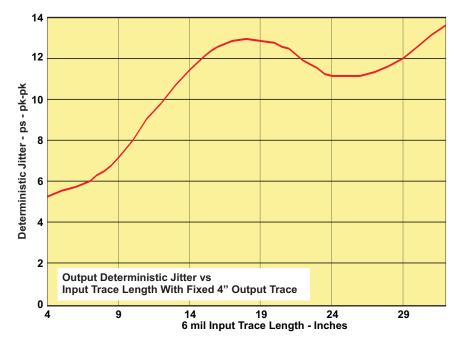


Figure 28. Jitter Performance Over Different Input Trace Lengths



Page

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### **REVISION HISTORY**

#### Changes from Original (April 2010 ) to Revision A

Changed in Table 1. Pin Description, signals: TX1+, TX1-, TX2+ and TX2-, I/O types changed from O, CML to O, VML also in Descripton, 'CML' to 'VML'



11-Apr-2013

### **PACKAGING INFORMATION**

Orderable Device	Status	Package Type	Package	Pins	Package	Eco Plan	Lead/Ball Finish	MSL Peak Temp	Op Temp (°C)	Top-Side Markings	Samples
	(1)		Drawing		Qty	(2)		(3)		(4)	
SN65LVPE502RGER	ACTIVE	VQFN	RGE	24	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	0 to 85	LVPE502	Samples
SN65LVPE502RGET	ACTIVE	VQFN	RGE	24	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	0 to 85	LVPE502	Samples

<sup>(1)</sup> The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

**LIFEBUY:** TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

**NRND:** Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

**PREVIEW:** Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

**TBD:** The Pb-Free/Green conversion plan has not been defined.

**Pb-Free (RoHS):** TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes. **Pb-Free (RoHS Exempt):** This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between

the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

<sup>(3)</sup> MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

(4) Multiple Top-Side Markings will be inside parentheses. Only one Top-Side Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Top-Side Marking for that device.

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# PACKAGE MATERIALS INFORMATION

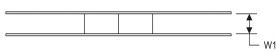
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### TAPE AND REEL INFORMATION

#### REEL DIMENSIONS

TEXAS INSTRUMENTS





TAPE AND REEL INFORMATION

#### TAPE DIMENSIONS



A0	Dimension designed to accommodate the component width
B0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

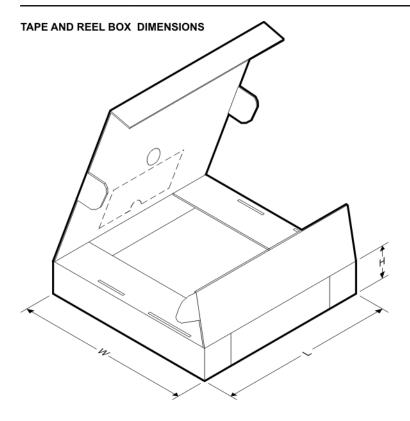
*All dimensions are nominal												
Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN65LVPE502RGER	VQFN	RGE	24	3000	330.0	12.4	4.25	4.25	1.15	8.0	12.0	Q2
SN65LVPE502RGET	VQFN	RGE	24	250	180.0	12.4	4.25	4.25	1.15	8.0	12.0	Q2

TEXAS INSTRUMENTS

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# PACKAGE MATERIALS INFORMATION

14-Jul-2012



\*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN65LVPE502RGER	VQFN	RGE	24	3000	367.0	367.0	35.0
SN65LVPE502RGET	VQFN	RGE	24	250	210.0	185.0	35.0

# **MECHANICAL DATA**



NOTES: A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M-1994.

- B. This drawing is subject to change without notice.
- C. Quad Flatpack, No-Leads (QFN) package configuration.
- D. The package thermal pad must be soldered to the board for thermal and mechanical performance.
- E. See the additional figure in the Product Data Sheet for details regarding the exposed thermal pad features and dimensions. F. Falls within JEDEC MO-220.
  - TEXAS INSTRUMENTS www.ti.com

## RGE (S-PVQFN-N24)

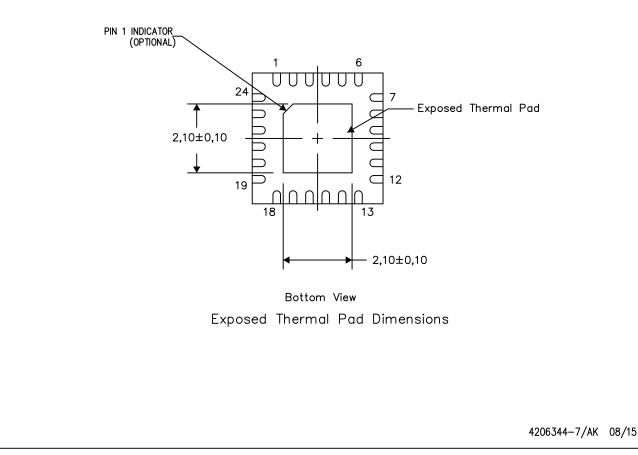
## PLASTIC QUAD FLATPACK NO-LEAD

### THERMAL INFORMATION

This package incorporates an exposed thermal pad that is designed to be attached directly to an external heatsink. The thermal pad must be soldered directly to the printed circuit board (PCB). After soldering, the PCB can be used as a heatsink. In addition, through the use of thermal vias, the thermal pad can be attached directly to the appropriate copper plane shown in the electrical schematic for the device, or alternatively, can be attached to a special heatsink structure designed into the PCB. This design optimizes the heat transfer from the integrated circuit (IC).

For information on the Quad Flatpack No-Lead (QFN) package and its advantages, refer to Application Report, QFN/SON PCB Attachment, Texas Instruments Literature No. SLUA271. This document is available at www.ti.com.

The exposed thermal pad dimensions for this package are shown in the following illustration.

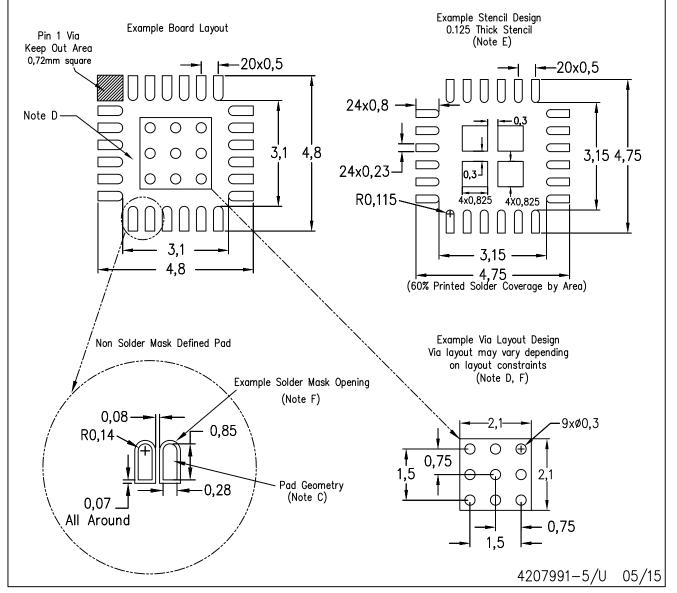


#### NOTES: A. All linear dimensions are in millimeters



# RGE (S-PVQFN-N24)

# PLASTIC QUAD FLATPACK NO-LEAD



NOTES:

- A. All linear dimensions are in millimeters.
  - B. This drawing is subject to change without notice.
  - C. Publication IPC-7351 is recommended for alternate designs.
  - D. This package is designed to be soldered to a thermal pad on the board. Refer to Application Note, Quad Flat-Pack Packages, Texas Instruments Literature No. SLUA271, and also the Product Data Sheets for specific thermal information, via requirements, and recommended board layout. These documents are available at www.ti.com <a href="http://www.ti.com">www.ti.com</a>.
  - E. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC 7525 for stencil design considerations.
  - F. Customers should contact their board fabrication site for recommended solder mask tolerances and via tenting recommendations for vias placed in the thermal pad.



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